Diode Semiconductor Device - Page 1 of 1



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Gla	ass
Ov	erall Length:
0.3	00 inches
Те	rminal Length:
1.0	00 inches
Ov	erall Diameter:
0.1	07 inches
Мо	ounting Method:
Те	rminal
Fea	atures Provided:
He	rmetically sealed case
Se	miconductor Material:
Sili	con
Vo	Itage Rating In Volts Per Characteristic:
50.	0 reverse voltage, peak
Cu	rrent Rating Per Characteristic:
10.	00 milliamperes forward current, average peak
Ма	ximum Operating Tempurature Per Measurement Point:
175	5.0 degrees celsius ambient air
Те	rminal Type And Quantity:
2 u	ninsulated wire lead
Sp	ecification Data:
801	131-release4070 professional/industrial association specification
Sh	elf Life:
N/a	a
Un	it Of Measure:
 De	militarization:
No	
Fiig	
	10a0